

SANYO**FC806**

Silicon Schottky Barrier Diode

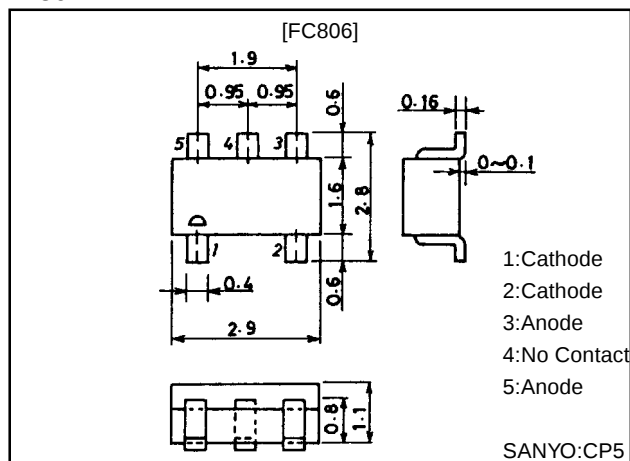
50V, 100mA Rectifier**Features**

- Low forward voltage (V_F max=0.55V) .
- Fast reverse recovery time (t_{rr} max=10ns) .
- Composite type with 2 diodes contained in the CP package currently in use, saving the mounting space greatly.
- The FC806 is formed with two chips, each being equivalent to the SB01-05CP, placed in one package.

Package Dimensions

unit:mm

1236A

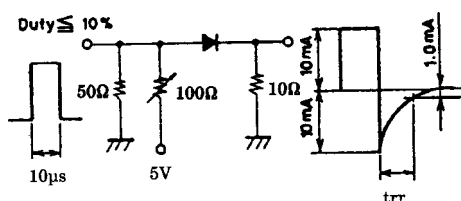
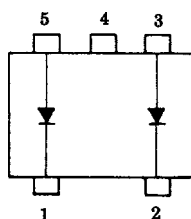
**Specifications****Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$**

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	V_{RRM}		50	V
Nonrepetitive Peak Reverse Surge Voltage	V_{RSM}		55	V
Average Output Current	I_O		100	mA
Surge Forward Current	I_{FSM}	50MHz sine wave, 1 cycle	2	A
Junction Temperature	T_j		-55 to +125	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +125	$^\circ\text{C}$

Electrical Characteristics at $T_a = 25^\circ\text{C}$

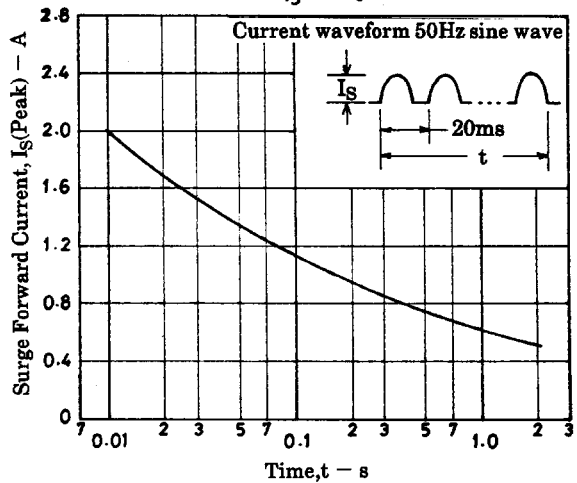
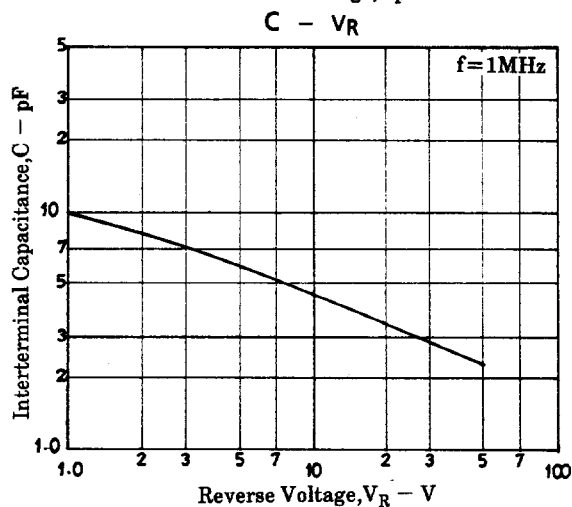
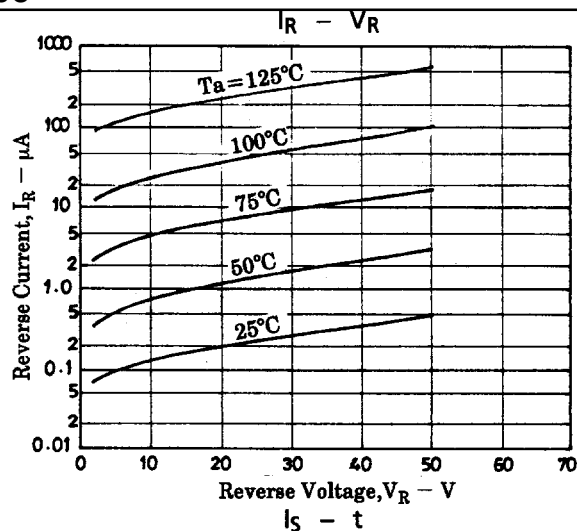
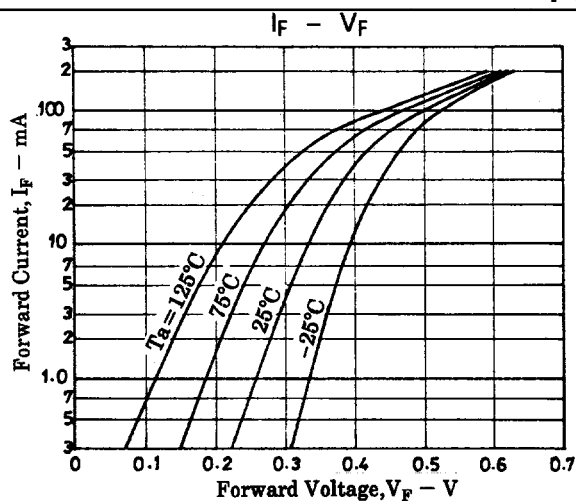
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Reverse Voltage	V_R	$I_R=50\mu\text{A}$	50			V
Forward Voltage	V_F	$I_F=100\text{mA}$			0.55	V
Reverse Current	I_R	$V_R=25\text{V}$			15	μA
Interteminal Capacitance	C	$V_R=10\text{V}$, $f=1\text{MHz}$		4.4		pF
Reverse Recovery Time	t_{rr}	$I_F=I_R=100\text{mA}$, See specified Test Circuit			10	ns
Thermal Resistance	$R_{th}(j-a)$			560		$^\circ\text{C/W}$

· Marking:806

 t_{rr} Test Circuit**Electrical Connection****SANYO Electric Co.,Ltd. Semiconductor Bussiness Headquarters**

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

22898HA (KT)/O3196G1/8030MH, TA, TS No.3401-1/2



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